TOSHIBA Bi-CMOS Digital Integrated Circuit Silicon Monolithic

TD74BC574P,TD74BC574F

Octal D-Type Flip-Flop with 3-State Outputs (Non-Inverted)

The TD74BC574P/TD74BC574F is a high-speed 8-bit flip-flop fabricated with silicon gate Bi-CMOS technology. It achieves the high-speed operation equivalent to the FAST family while maintaining the Bi-CMOS low-power dissipation.

The TD74BC574P/F is a non-inverting flip-flop. Each bit is individually controlled by a clock input (CK) and an output enable input (\overline{OE}). When the \overline{OE} input is high, all eight outputs are in the high-impedance state, which facilitates the interface with bus lines.

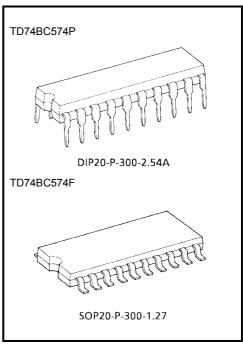
All inputs are equipped with resistors and diodes to protect against Electrostatic Discharge (ESD).

Features

- High-speed operation $t_{pd} = 8.8 \text{ ns (typ.)}$
- Symmetrical output impedance IOH = -3 mA (max)

IOL = 24 mA (max)

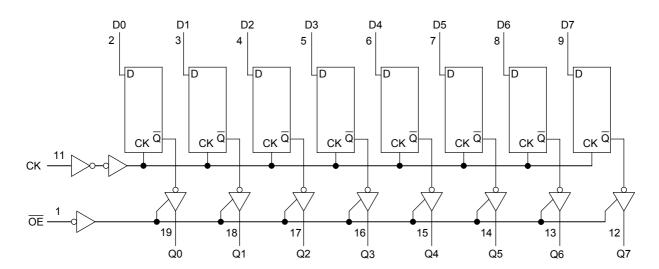
- Low power dissipation ICCD = 7 mA (typ.)
 - $ICCZ = 10 \mu A \text{ (typ.)}$
- Operating temperature range Ta = -40°C to 85°C
- High ESD protection2000 V (MIL standard)
- Pin and function compatible with FAST (74F574)



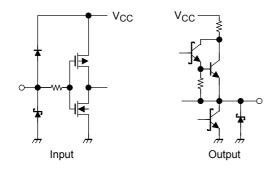
Weight

DIP20-P-300-2.54A: 1.48 g (typ.) SOP20-P-300-1.27: 0.25 g (typ.)

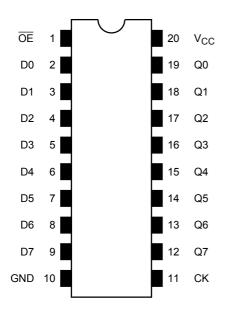
Logic Diagram



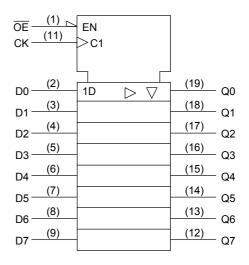
Input Protection Circuit and Output Equivalent Circuit



Pin Assignment (top view)



Logic Symbol



Truth Table

	Outputs		
ŌĒ	CK	D	Q
Н	Х	Х	Z
L	$\overline{}$	Х	Qn
L	_	L	L
L		Н	Н

X: Don't care

Z: High impedance

Qn: No change

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Absolute Maximum Ratings

Characteristi	cs	Symbol	Rating	Unit	
Power supply voltage		V _{CC}	-0.5 to 7.0	V	
Input voltage		V _{IN}	-1.2 to V _{CC} + 0.5	V	
Output voltage		VO	-0.5 to $V_{CC} + 0.5$	٧	
Input clamp diode current		I _{IK}	±30	mA	
Output clamp diode current		lok	-30	mA	
Output current (output lo	Output current (output low state)		48	mA	
Dower dissination	BC574P	D-	1380 (Note 1)	mW	
Power dissipation	BC574F	P _D	860 (Note 1)	IIIVV	
Storage temperature		T _{stg}	-65 to 150	°C	

Note 1: $Ta = 25^{\circ}C$

Recommended Operating Conditions

Characteristics		Symbol	Min	Тур.	Max	Unit	
Power supply voltage	V _{CC}	4.5	5.0	5.5	V		
Input voltage	V _{IN}	0	_	V _{CC}	٧		
Output voltage		V _O	0	_	V_{CC}	V	
Output current	High level	I _{OH}	_	_	-3	mA	
Output current	Low level	l _{OL}	_		24	IIIA	
Operating temperature		T _{opr}	-40	25	85	°C	

Electrical Characteristics

DC Characteristics (unless otherwise specified, $V_{CC} = 4.5 \text{ V}$ to 5.5 V, $Ta = -40^{\circ}\text{C}$ to 85°C)

Characteristics		Symbol	Test Condition	V _{CC}	Min	Typ. (Note 1)	Max	Unit
Input voltage	High level	V_{IH}	_	_	2.0	_	_	V
input voitage	Low level	V_{IL}	_	_	_	_	0.8	v
Input clamp voltage		V_{IK}	I _{IK} = -18 mA	4.5	_	_	-1.2	٧
	High level	V_{OH}	$I_{OH} = -3.0 \text{ mA}$	4.5	2.4	3.4	_	
Output voltage	riigirievei	VOH	$I_{OH} = -3.0 \text{ mA}$	4.75	2.7	3.4	_	V
	Low level	V_{OL}	I _{OL} = 24 mA	4.5		_	0.5	
		l _l	$V_{IN} = V_{CC}$	5.5	_	_	±1.0	
Input current (all input p	oins)	l _{IH}	$V_{IN} = 2.7 \text{ V}$	5.5	_	_	±1.0	μА
		I _{IL}	V _{IN} = 0.5 V or GND	V or GND 5.5 — ±1.0 V 5.5 — 50				
3-state OFF leakage cu	etete OFF leekens augment		V _O = 2.7 V	5.5 — —		50	Δ	
3-State OFF leakage Ct	JITEIIL	I _{OZL}	V _O = 0.5 V	5.5	_	_	-50	μΑ
Output short current (Note 2)		I _{OS}	$V_O = GND$	5.5	-60	_	-180	mA
Quiescent supply current (total)		I _{CCL}	$V_{IN} = V_{CC}$ or ground All outputs are low.	5.5		20	27	mA
		Іссн	$V_{IN} = V_{CC}$ or ground All outputs are high.	5.5	_	10	50	
		I _{CCZ}	V _{IN} = V _{CC} or ground All outputs are in the high-impedance state.	5.5	_	10	50	μА
Quiescent supply current (each bit)		Δlcc1	One input: $V_{IN} = 0.5 \text{ V}$ Other inputs: V_{CC} or GND	_	_		1.5	- mA
		Δl _{CC2}	One input: $V_{IN} = V_{CC} - 2.1 \text{ V}$ Other inputs: V_{CC} or GND	_	—		1.5	IIIA

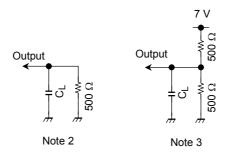
Note 1: Typical value is measured at $V_{CC} = 5.0 \text{ V}$ and $Ta = 25^{\circ}\text{C}$.

Note 2: Only one output at a time should be shorted. Duration should not exceed one second.

AC Characteristics (Input $t_r = t_f = 2.5 \text{ ns}$)

Characteristics		Symbol Test Condition	Ta = 25°C V _{CC} = 5.0 V			$Ta = -40^{\circ}$ $V_{CC} = 5.0$	Unit		
		Cymbol	rest condition	Min	Тур.	Max	Min	Max	Onit
Propagation delay time	CK-Q	t _{pLH}		3.0	8.8	11.5	3.0	13.0	ns
Tropagation delay time	OIT Q	t _{pHL}		3.0	8.8	11.0	3.0	13.0	
2 state system to analyte times	OE -Q	t _{pZH}	C _L = 50 pF	3.0	10.4	12.5	3.0	14.5	ns
3-state output enable time		t _{pZL}		3.0	8.2	9.5	3.0	13.5	
3 state output disable time	OE -Q	t _{pHZ}		3.0	6.5	9.5	3.0	11.5	ns
3-state output disable time		t _{pLZ}		3.0	5.8	8.5	3.0	10.0	115
Maximum clock frequency		f _{MAX}		100	_	_	70	_	MHz
Dynamic supply current		I _{CCD}	f = 1 MHz Output open	_	7	12	_	15	mA

Note 1: When measuring t_{pLH} , t_{pHL} , t_{pZH} and t_{pHZ} , the output pin should be connected as shown in Note 2. When measuring t_{pZL} , and t_{pLZ} , the output pin should be connected as shown in Note 3.

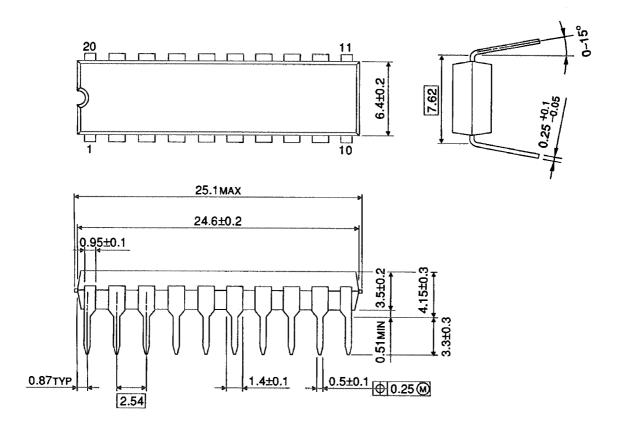


AC Characteristics (Input $t_r = t_f = 2.5 \text{ ns}$)

Characteristics		Symbol	Test Condition	Ta = 25°C V _{CC} = 5.0 V			$Ta = -40^{\circ}$ $V_{CC} = 5.0$		
		Cymbol		Min	Тур.	Max	Min	Max	Onit
Pulse width	СК	t _{w (L)}		6	_	_	6	_	ns
	CK	t _{w (H)}		7	_	_	7	_	115
Setup time	D-CK	t _{s (L)}	C _L = 50 pF	2	_	_	2	_	ns
		t _{s (H)}	$R_L = 500 \Omega$	2	_	_	2	_	115
Hold time	D-CK	t _{h (L)}		2	_	_	2	_	ns
		t _{h (H)}		2	_	_	2	_	115

Package Dimensions

DIP20-P-300-2.54A Unit: mm

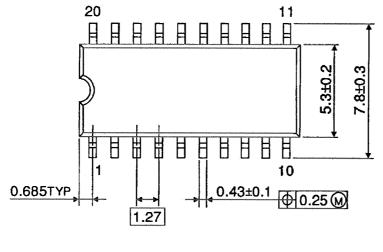


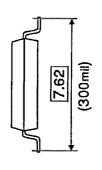
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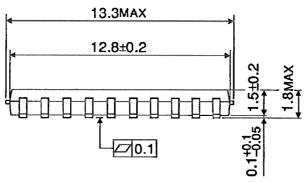
Weight: 1.48 g (typ.)

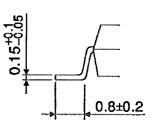
Package Dimensions

SOP20-P-300-1.27 Unit: mm









Weight: 0.25 g (typ.)

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